

## **NCE N-Channel Super Trench Power MOSFET**

#### **Description**

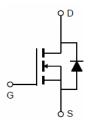
The NCEP15T14T uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

#### **General Features**

- $V_{DS} = 150V, I_D = 140A$  $R_{DS(ON)} < 6.2 m\Omega @ V_{GS} = 10V$
- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

#### **Application**

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification



Schematic diagram



TO-247 top view

100% UIS TESTED!

100% ΔVds TESTED!

#### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP15T14T	NCEP15T14T	TO-247	-	-	-

#### Absolute Maximum Ratings (T<sub>C</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	150	V
Gate-Source Voltage	V <sub>G</sub> s	±20	V
Drain Current-Continuous	I <sub>D</sub>	140	А
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	100	А
Pulsed Drain Current	I <sub>DM</sub>	560	А
Maximum Power Dissipation	P <sub>D</sub>	320	W
Derating factor		2.1	W/°C
Single pulse avalanche energy (Note 5)	Eas	1296	mJ
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	$^{\circ}$

#### **Thermal Characteristic**

Thermal Resistance,Junction-to-Case <sup>(Note 2)</sup>	$R_{ heta JC}$	0.47	°C/W

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## Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Off Characteristics							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	150	-	-	V	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =150V,V <sub>GS</sub> =0V	-	-	1	μA	
Gate-Body Leakage Current I <sub>GSS</sub> V <sub>GS</sub> =±20		$V_{GS}$ =±20 $V$ , $V_{DS}$ =0 $V$	-	-	±100	nA	
On Characteristics (Note 3)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_D=250\mu A$	2.0	3.0	4.0	V	
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =70A	-	5.6	6.2	mΩ	
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =10V,I <sub>D</sub> =70A	70	-	-	S	
Dynamic Characteristics (Note4)	1		•				
Input Capacitance	C <sub>lss</sub>	)/ 75)/)/ O)/	-	5500	7150	PF	
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =75V, $V_{GS}$ =0V, F=1.0MHz	-	690	890	PF	
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.UMHZ	-	24	31	PF	
Switching Characteristics (Note 4)	Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	26	-	nS	
Turn-on Rise Time	t <sub>r</sub>	V <sub>DD</sub> =75V,I <sub>D</sub> =70A	-	36	-	nS	
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{G}$ =4.7 $\Omega$	-	47	-	nS	
Turn-Off Fall Time	t <sub>f</sub>		-	15	-	nS	
Total Gate Charge	Qg	\/ -75\/  -704	-	80	104	nC	
Gate-Source Charge	$Q_{gs}$	V <sub>DS</sub> =75V,I <sub>D</sub> =70A,	-	32	41	nC	
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	22	28	nC	
Drain-Source Diode Characteristics							
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	$V_{GS}$ =0 $V$ , $I_F$ = $I_S$	-		1.2	V	
Diode Forward Current (Note 2)	Is		-	-	140	Α	
Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> = 25°C, I <sub>F</sub> = I <sub>S</sub>	-	140		nS	
Reverse Recovery Charge	Qrr	di/dt = 100A/μs <sup>(Note3)</sup>	-	498		nC	

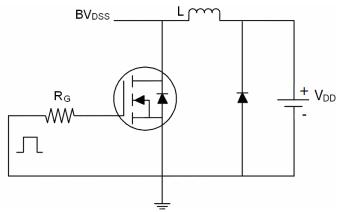
#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board,  $t \le 10$  sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25  $^{\circ}\text{C}$  ,VDD=50V,VG=10V,L=0.5mH,Rg=25 $\Omega$

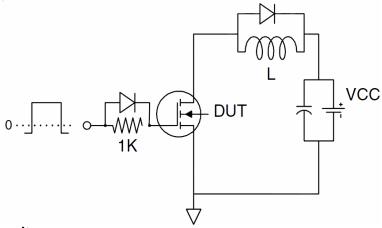


### **Test Circuit**

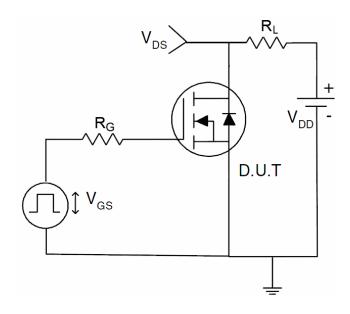
## 1) E<sub>AS</sub> test Circuit



## 2) Gate charge test Circuit

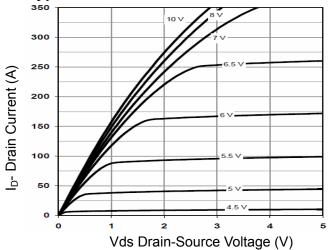


#### 3) Switch Time Test Circuit

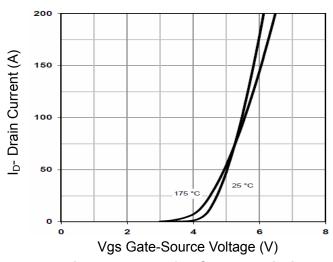




### **Typical Electrical and Thermal Characteristics**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

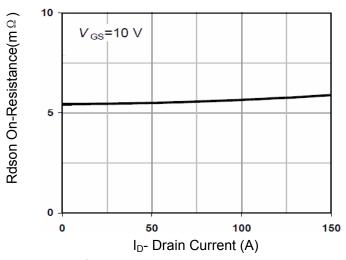


Figure 3 Rdson- Drain Current

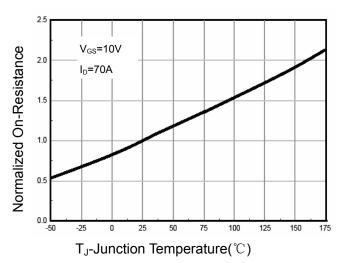


Figure 4 Rdson-JunctionTemperature

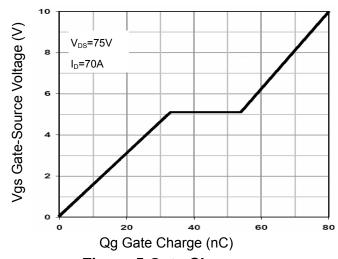


Figure 5 Gate Charge

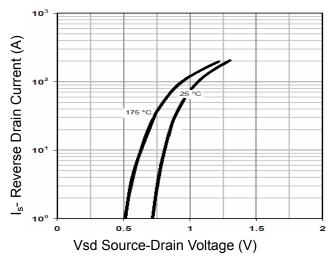
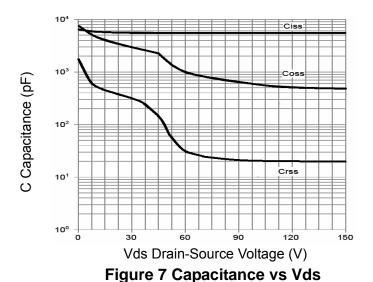
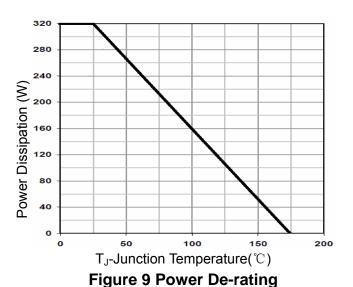
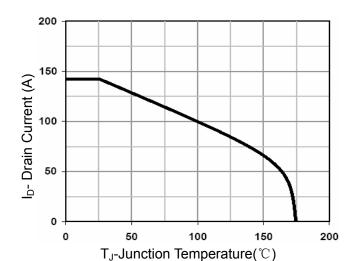


Figure 6 Source- Drain Diode Forward









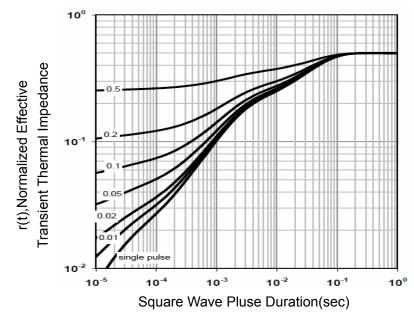
Vds Drain-Source Voltage (V)
Figure 8 Safe Operation Area

10<sup>1</sup>

10°

10<sup>-1</sup>

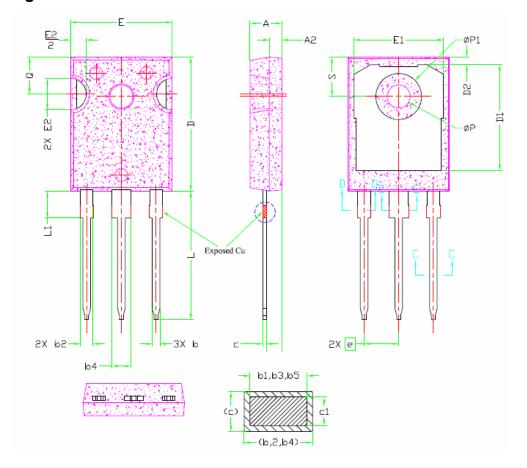
Figure 10 Current De-rating



**Figure 11 Normalized Maximum Transient Thermal Impedance** 



# **TO-247 Package Information**



01/11/01				
SYMBOL	MIN.	NOM.	MAX.	NOTES
Α	4.83	5.02	5,21	
A1	2.29	2.41	2.55	
A2	1,50	2.00	2.49	
ь	1.12	1.20	1.33	
b1	1.12	1.20	1.28	
b2	1.91	2.00	2.39	6
b3	1.91	2.00	2.34	
b4	2.87	3.00	3.22	6,8
b5	2.87	3.00	3.18	
С	0.55	0.60	0.69	6
c1	0.55	0.60	0.65	
D	20,80	20,95	21,10	4
D1	16,25	16,55	17,65	5
D2	0.51	1,19	1,35	
E	15,75	15.94	16,13	4
E1	13.46	14.02	14,16	5
E2	4.32	4.91	5.49	3
e				
L	19.81	20.07	20,32	
L1	4.10	4.19	4.40	6
ØP	3.56	3.61	3.65	7
ØP1	7.19REF			
Q	5,39	5.79	6.20	
S	6.04	6.17	6.30	



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